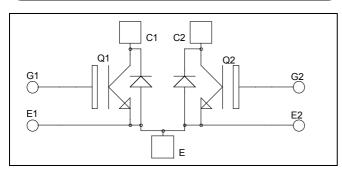


Dual common source Fast Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 1200V$$

 $I_{C} = 150A$ @ $Tc = 80$ °C



Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Fast Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
т	Continuous Collector Current	$T_C = 25$ °C	220	
I_{C}	Continuous Conector Current	$T_C = 80$ °C	150	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	350	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	690	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	300A @ 1150V	

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				350	μΑ
V	Collector Emitter Saturation Voltage	, GE 10 ,	$T_j = 25$ °C		1.7	2.1	V
$V_{CE(sat)}$			$T_j = 125$ °C		2.0		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 3 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V$		10.7		
C_{oes}	Output Capacitance	$V_{CE} = 25V$		0.56		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		0.48		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		280		ns
T_{r}	Rise Time	$V_{GE} = \pm 15V$		40		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 150A$		420		
T_{f}	Fall Time	$R_{G} = 2.2\Omega$		75		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C	C)	290		
T_{r}	Rise Time	$V_{GE} = \pm 15V$		45		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 150A$		520		
T_{f}	Fall Time	$R_G = 2.2\Omega$		90		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V \ V_{Bus} = 600V$ $T_j = 125^{\circ}C$		14		mJ
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$I_C = 150A$ $R_G = 2.2\Omega$ $T_j = 125^{\circ}C$		16		1113

Diode ratings and characteristics

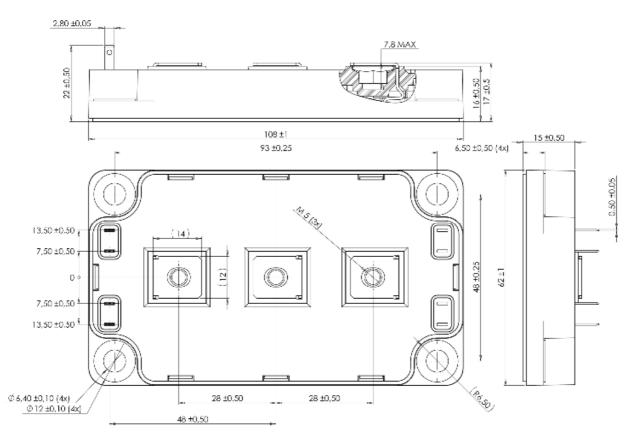
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25$ °C			250	μΑ
-KIVI	Transmitter (0.50 Bounday Current	' K 1200 '	$T_j = 125$ °C			600	per 1
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		150		A
V_{F}	Diode Forward Voltage	$I_{\rm F} = 150A$	$T_i = 25^{\circ}C$		1.6	2.1	V
v F	Diode Polward Voltage	1 _F - 130A	$T_i = 125$ °C		1.6		
t_{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		170		ns
٩rr	reverse recovery Time	1.504	$T_{j} = 125^{\circ}C$		280		115
Q_{rr}	Reverse Recovery Charge	$I_F = 150A$ $V_R = 600V$ $di/dt = 2500A/\mu s$	$T_j = 25^{\circ}C$		14		μС
Qrr	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		28		μС
E_{r}	Poverse Posesyery Energy		$T_i = 25^{\circ}C$		6		mJ
\mathbf{L}_{r}	Reverse Recovery Energy		$T_j = 125$ °C		11		1113



Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Lightion to Case Thermal Resistance		IGBT			0.18	°C/W
			Diode			0.30	C/ VV
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{\rm J}$	Operating junction temperature range Storage Temperature Range			-40		150	
T_{STG}				-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight	·				300	g

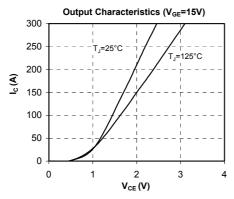
SP6 Package outline (dimensions in mm)

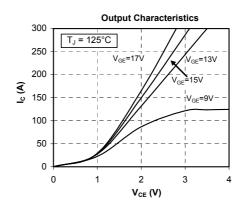


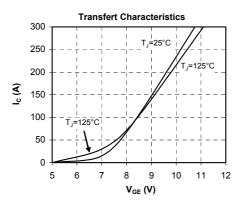
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

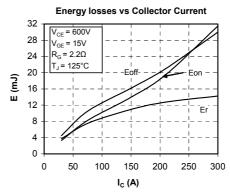


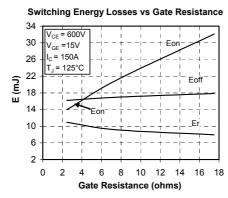
Typical Performance Curve

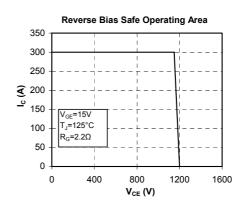


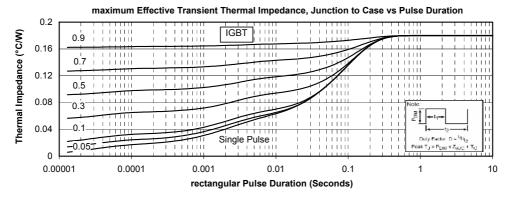




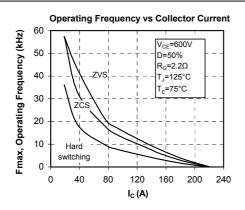


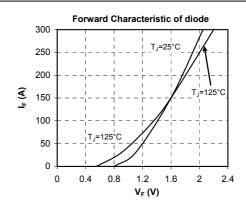


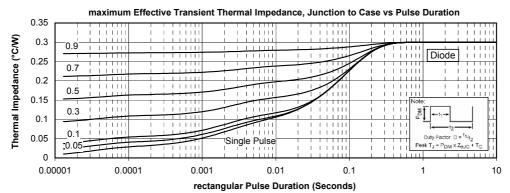












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